

GLF71300

Nano-Current Consumed, I_QSmart[™] LoadSwitch with Slew Rate Control

Product Brief

DESCRIPTION

Rev. 1.4 Feb 2022

The GLF71300 is an ultra-efficiency, 2.0 A rated, Load Switch with integrated slew rate control. The best in class efficiency makes it an ideal choice for use in IoT, mobile, and wearable electronics.

The GLF71300 features an ultra-efficient I_QSmart^{TM} technology that supports the lowest quiescent current (I_Q) and shutdown current (I_{SD}) in the industry. Low I_Q and I_{SD} solutions help designers to reduce parasitic leakage current, improve system efficiency, and increase battery lifetime.

The GLF71300 integrated slew rate control can also enhance system reliability by mitigating bus voltage swings during switching events. Where uncontrolled switches can generate high inrush currents that result in voltage droop and/or bus reset events, the GLF slew rate control specifically limits inrush current during turn-on to minimize voltage droop.

The GLF71300 Load Switch device supports an industry leading wide input voltage range and helps to improve operating life and system robustness. Furthermore, one device can be used in multiple voltage rail applications which helps to simplify inventory management and reduces operating cost.

The GLF71300 Load Switch device is small utilizing a wafer level chip scale package with 4 bumps in a 0.77 mm x 0.77 mm x 0.46 mm die size and a 0.4 mm bump pitch.

FEATURES

Ultra-Low I_Q: 1 nA Typ @ 5.5 V_{IN}
Ultra-Low I_{SD}: 19 nA Typ @ 5.5 V_{IN}

• Low $R_{ON} = 34 \text{ m}\Omega \text{ Typ.} @ 5.5 \text{ V}_{IN}$

Iout Max = 2.0 A

Wide Input Range: 1.1 V to 5.5 V

6 Vabs max

Controlled Rise Time: 430 us at 3.3 V_{IN}

Internal EN Pull-Down Resistor

• Ultra-Small: 0.77 mm x 0.77 mm

APPLICATIONS

Wearables

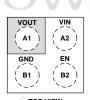
Data Storage, SSD

Mobile Devices

Low Power Subsystems





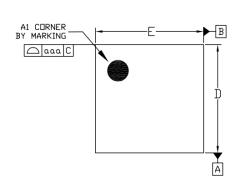


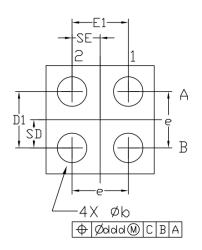


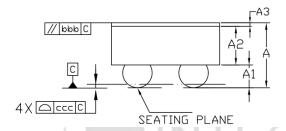
0.77 mm x 0.77 mm x 0.46 mm WLCSP

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PACKAGE OUTLINE







Dimensional Ref.									
REF.	Min.	Nom.	Max.						
Α	0.410	0.460	0.510						
Α1	0.135	0.160	0.185						
Α2	0.250	0.275	0.300						
Α3	0.020	0.025	0.030						
D	0.755								
Ε	0.755	0.770	0.785						
D1	0.350	0.400	0.450						
E1	0.350	0.400	0.450						
Ь	0.170	0.210	0.250						
e 0.400 BSC									
SD 0.200 BSC									
SE	SE 0.200 BSC								
Tol. of Form&Position									
ааа	aaa 0.10								
ЬЬЬ	ЬЬ 0.10								
CCC	ccc 0.05								
ddd	ddd 0.05								

RATED POWER

Notes

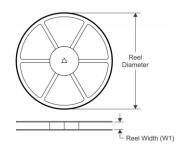
- 1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGRESS)
- 2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
- 3. A3: BACKSIDE LAMINATION

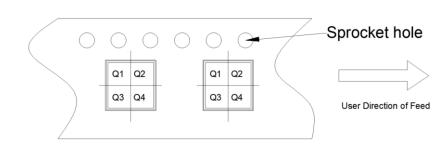
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TAPE AND REEL INFORMATION

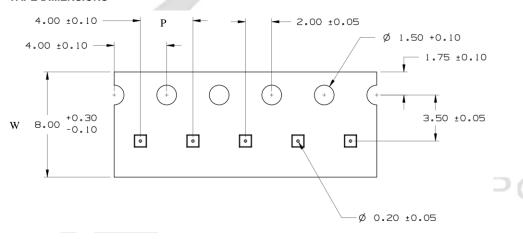
REEL DIMENSIONS

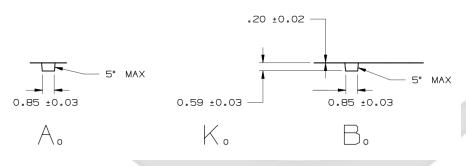
QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE





TAPE DIMENSIONS





Device	Package	Pins	SPQ	Reel Diameter(mm)	Reel Width W1	Α0	В0	КО	Р	w	Pin1
GLF71300	WLCSP	4	4000	180	9	0.85	0.85	0.59	4	8	Q1

Remark:

- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- C0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P: Pitch between successive cavity centers